## **SIEMENS**

Data sheet 3RF2120-1AA02



Semiconductor relay, 1-phase 3RF2 Width 22.5 mm, 20 A 24-230 V / 24 V DC screw terminal

product brand name	SIRIUS
product designation	solid-state relay
design of the product	single-phase
product type designation	3RF21
manufacturer's article number	
<ul><li>_1 of the accessories that can be ordered</li></ul>	3RF2900-3PA88
<ul><li>_2 of the accessories that can be ordered</li></ul>	3RF2920-0HA13
<ul><li>_3 of the accessories that can be ordered</li></ul>	3RF2900-0EA18
<ul><li>_4 of the accessories that can be ordered</li></ul>	3RF2920-0GA13
<ul><li>_5 of the accessories that can be ordered</li></ul>	3RF2920-0FA08
product designation	
<ul><li>_1 of the accessories that can be ordered</li></ul>	terminal cover
<ul><li>_2 of the accessories that can be ordered</li></ul>	power regulator
<ul><li>_3 of the accessories that can be ordered</li></ul>	converter
<ul><li>_4 of the accessories that can be ordered</li></ul>	load monitoring
<ul><li>_5 of the accessories that can be ordered</li></ul>	load monitoring, basis
General technical data	
product function	zero-point switching
power loss [W] for rated value of the current	
<ul> <li>at AC in hot operating state</li> </ul>	28.6 W
<ul> <li>at AC in hot operating state per pole</li> </ul>	28.6 W
without load current share typical	0.4 W
insulation voltage rated value	600 V
type of voltage	
<ul> <li>of the operating voltage</li> </ul>	AC
of the control supply voltage	DC
surge voltage resistance of main circuit rated value	6 kV
protection class IP	IP20
protection class IP on the front according to IEC 60529	IP20
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8
Weight	0.071 kg
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0

type of voltage of the operating voltage	AC
operating voltage	AU
at AC	
	24 230 V
— at 50 Hz rated value	24 230 V
— at 60 Hz rated value	50 60 Hz
operating frequency rated value	
relative symmetrical tolerance of the operating frequency	10 %
operating range relative to the operating voltage at AC	00 050 //
• at 50 Hz	20 253 V
• at 60 Hz	20 253 V
operational current	20.4
at AC-51 rated value	20 A 20 A
according to UL 508 rated value	100 mA
operational current minimum	
rate of voltage rise at the thyristor for main contacts maximum permissible	500 V/μs
blocking voltage at the thyristor for main contacts maximum permissible	800 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	200 A
I2t value maximum	200 A²-s
Control circuit/ Control	
type of voltage of the control supply voltage	DC
control supply voltage 1 at DC rated value maximum permissible	30 V
control supply voltage 1 at DC	15 24 V
control supply voltage	
at DC initial value for signal <1> detection	15 V
• at DC full-scale value for signal<0> recognition	5 V
control current at minimum control supply voltage	
• at DC	13 mA
control current at DC rated value	15 mA
ON-delay time	1 ms; additionally max. one half-wave
OFF-delay time	1 ms; additionally max. one half-wave
Auxiliary circuit	
type of switching contact	normally open contact (NO)
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method side-by-side mounting	Yes
fastening method	screw fixing
design of the thread of the screw for securing the equipment	M4
tightening torque of fixing screw maximum	1.5 N·m
tightening torque [lbf·in] of fixing screw maximum	13 lbf-in
height	85 mm
width	22.5 mm
depth	48 mm
Connections/ Terminals	
product component removable terminal for auxiliary and control circuit	Yes
type of electrical connection	
for main current circuit	screw-type terminals
for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	
<ul> <li>for main contacts</li> </ul>	
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
<ul><li>— solid</li><li>— finely stranded with core end processing</li></ul>	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²

solid or stranded	1.5 6 mm²
finely stranded with core end processing	1 10 mm²
type of connectable conductor cross-sections	
<ul> <li>for auxiliary and control contacts</li> </ul>	
— solid	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
<ul> <li>finely stranded with core end processing</li> </ul>	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
<ul> <li>finely stranded without core end processing</li> </ul>	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
for AWG cables for auxiliary and control contacts	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for main contacts	14 10
tightening torque	
<ul> <li>for main contacts with screw-type terminals</li> </ul>	2 2.5 N·m
<ul> <li>for auxiliary and control contacts with screw-type terminals</li> </ul>	0.5 0.6 N·m
tightening torque [lbf·in]	
<ul> <li>for main contacts with screw-type terminals</li> </ul>	7 10.3 lbf-in
<ul> <li>for auxiliary and control contacts with screw-type terminals</li> </ul>	4.5 5.3 lbf-in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
• for main contacts	7 mm
for auxiliary and control contacts	7 mm
Electrical Safety	
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	
installation altitude at height above sea level maximum	1 000 m
ambient temperature	
during operation	-25 +60 °C
during storage	-55 +80 °C
Electromagnetic compatibility	
conducted interference	01///5111 1 1 1 1 1 2
<ul> <li>due to burst according to IEC 61000-4-4</li> </ul>	2 kV / 5 kHz behavior criterion 2
due to conductor-earth surge according to IEC 61000-4-5	2 kV behavior criterion 2
<ul> <li>due to conductor-conductor surge according to IEC 61000-4-5</li> </ul>	1 kV behavior criterion 2
• due to high-frequency radiation according to IEC 61000-4-6	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
4-6	
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	80 MHz 1 GHz 10 V/m, behavior criterion 1
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0
4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH	80 MHz 1 GHz 10 V/m, behavior criterion 1  4 kV contact discharging / 8 kV air discharging, behavior criterion 2  Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0  5SE1325
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0 5SE1325 3NE8015-1
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0 5SE1325 3NE8015-1 3NC1032
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  of gS fuse for semiconductor protection at NH design usable of full range R fuse link for semiconductor protection at cylindrical design usable of back-up R fuse link for semiconductor protection at NH design usable of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430
field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number  • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at the design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse	80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment  Class B for the domestic, business and commercial environments  3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1032 3NC2225

relays

manufacturer's article number

• of NEOZED fuse usable

5SE2306; These fuses have a smaller rated current than the semiconductor relays

## **Approvals Certificates**

**General Product Approval** 

**EMV** 



Confirmation









**Test Certificates** 

other

Railway

**Environment** 

Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

## Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2120-1AA02

Cax online generator

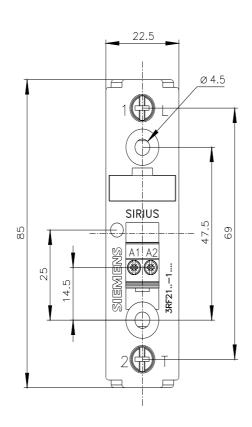
 $\underline{\text{http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en\&mlfb=3RF2120-1AA02}$ 

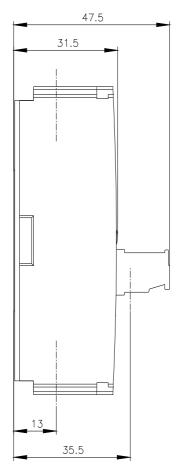
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

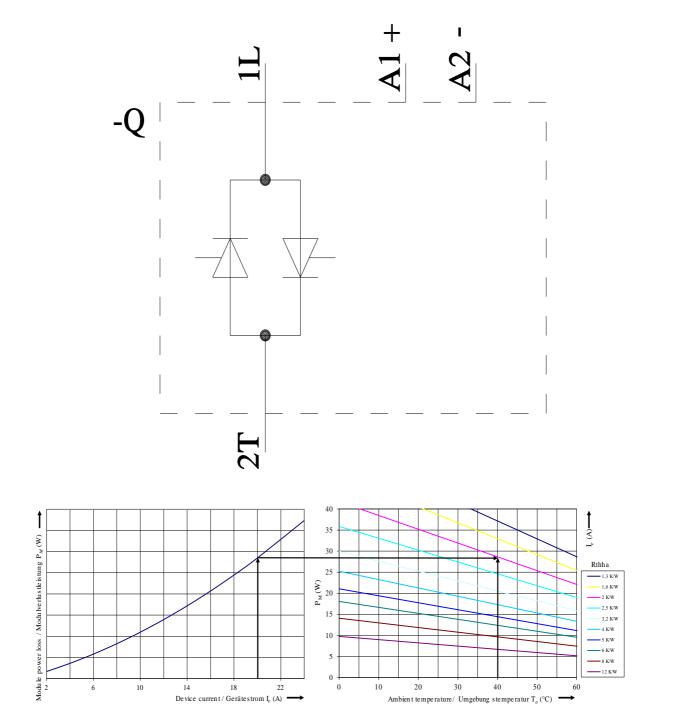
https://support.industry.siemens.com/cs/ww/en/ps/3RF2120-1AA02

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

http://www.automation.siemens.com/bilddb/cax\_de.aspx?mlfb=3RF2120-1AA02&lang=en







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